

### **Vishay Siliconix**

### High Voltage 4 $\Omega$ Quad SPST CMOS Analog Switch

#### DESCRIPTION

The DG454 series has four independently selectable high voltage (44 V) SPST switches, each with a typical on resistance of 4  $\Omega$  and a typical flatness of 0.2  $\Omega$ , ideal parameters for low distortion audio signal switching.

The DG454 (NC) and DG455 (NO) are identical except for the digital logic control input, which is inverted as shown in the Truth Table. The DG456 has two normally closed and two normally open switches.

These are high voltage switches that are fully specified with dual supplies at  $\pm 5$  V and  $\pm 15$  V and a single supply of 12 V. Fast switching speeds coupled with high signal bandwidth makes these parts suitable for video switching applications.

All digital inputs have 0.8 V and 2.4 V logic thresholds ensuring low voltage TTL/CMOS compatibility. Each switch conducts equally well in both directions when on and can handle an input signal range that extends to the supply voltage rails.

The DG454 DG455 and DG456 are pin compatible with the DG411, DG412 and DG413, except they require no V<sub>1</sub> supply.

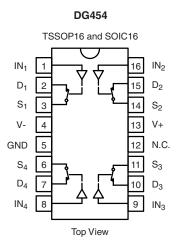
#### **FEATURES**

- Low on-resistance (4  $\Omega$  typical)
- On-resistance flatness (0.2  $\Omega$  typical)
- 100 mA continuous current
- 44 V supply maximum rating
- ± 15 V analog signal range
- Fully specified at supply voltages of  $\pm 5$  V, 12 V and ± 15 V
- No V<sub>1</sub> required
- Fast switching speed:
- t<sub>on</sub> 80 ns
- t<sub>off</sub> 60 ns
- TTL/CMOS compatible
- ESD protection 2 kV
- Pin compatible with DG411, DG412, and DG413, except no V<sub>1</sub> required
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Audio and video signal switching
- Precision automatic test equipment
- Precision data acquisition
- Relay replacement
- Communications systems
- Automotive and avionics applications
- Sample and hold systems

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE								
Logic	DG454	DG455						
0	On	Off						
1	Off	On						

TSSOP16 and SOIC16  $IN_1$ 16  $IN_2$ D₁ 5  $D_2$  $S_1$ S<sub>2</sub> 14 V-L٧ GND N.C.  $S_3$  $S_4$ 10 D<sub>3</sub> D₄ 9 8 IN<sub>3</sub>  $IN_4$ Top View

DG456

TRUTH TABLE								
Logic	$SW_1, SW_4$	$SW_2, SW_3$						
0	Off	On						
1	On	Off						

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### Vishay Siliconix



ORDERING INFORMATION							
Temp. Range	Package	Part Number					
DG454, DG455, DG456							
	16 Pin TSSOP	DG454EQ-T1-E3 DG455EQ-T1-E3 DG456EQ-T1-E3					
- 40 °C to 125 °C <sup>a</sup>	16 Pin Narrow SOIC	DG454EY-T1-E3 DG455EY-T1-E3 DG456EY-T1-E3					

Notes:

a. - 40 °C to 85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RAT	<b>FINGS</b> (T <sub>A</sub> = 25 °C, unless ot	herwise noted)		
Parameter	Limit	Unit		
V+ to V-		44		
GND to V-		25	v	
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>	(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first			
Continuous Current (D, S only)		100		
Peak Current, S or D (Pulsed 1 ms, 10 %	6 Duty Cycle)	300	– mA	
Storage Temperature		- 65 to 150	°C	
	16 Pin TSSOP <sup>c</sup>	450		
Power Dissipation (Package) <sup>b</sup>	16 Pin Narrow SOIC <sup>d</sup>	600	mW	
	16 Pin TSSOP	178	0000	
Thermal Resistance (Package) <sup>b</sup>	16 Pin Narrow SOIC	125	°C/W	
ESD (HBM)		2	kV	

Notes:

a. Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 5.6 mW/°C above 70 °C.

d. Derate 8 mW/°C above 75 °C.

SPECIFICATIONS FOR DUAL SUPPLIES									
Demonstern	Symbol	Test Conditions Unless Specified	Temp. <sup>b</sup>	h	- 40 °C to 125 °C - 40 °C			to 85 °C	Unit
Parameter	Symbol	V+ = 15 V, V- = - 15 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	remp."	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit
Analog Switch					•				
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	V
On-Resistance	R <sub>ON</sub>	$I_{\rm S}$ = - 10 mA, $V_{\rm D}$ = - 10 V to + 10 V	Room Full	3.8		5.3 8.3		5.3 7.3	
On-Resistance Match	$\Delta R_{ON}$	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = ± 10 V	Room Full	0.12		0.5 1		0.5 0.5	Ω
On-Resistance Flatness	R <sub>FLATNESS</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = - 5 V, 0 V, + 5 V	Room Full	0.25		0.5 0.5		0.5 0.5	
Switch Off	I <sub>S(off)</sub>		Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	
Leakage Current	I <sub>D(off)</sub>	$V_D = \pm 10 \text{ V}, \text{ V}_S = 10 \text{ V}$ $\mp$	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	nA
Channel On Leakage Current	I <sub>D(on)</sub>	$V_{S} = V_{D} = \pm 10 V$	Room Full	± 0.1	- 1 - 40	1 40	- 1 - 5	1 5	

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# DG454, DG455, DG456 Vishay Siliconix

SPECIFICATIONS	SPECIFICATIONS FOR DUAL SUPPLIES								
Parameter	Symbol	Test Conditions Unless Specified	Temp. <sup>b</sup>	o. <sup>b</sup> Typ. <sup>c</sup>	- 40 °C to 125 °C		- 40 °C	to 85 °C	Unit
i didileter	Symbol $V_+ = 15 V$ , $V = -15 V$ Temp. <sup>b</sup> Typ $V_{1N} = 2.4 V$ , $0.8 V^a$ $V_{1N} = 2.4 V$ $V_{1N$	iyp.	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	onic		
Digital Control		•							
Input Current, V <sub>IN</sub> Low	IIL	V <sub>IN</sub> Under Test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μA
Input Current, V <sub>IN</sub> High	Ι <sub>ΙΗ</sub>	V <sub>IN</sub> Under Test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μΑ
Input Capacitance <sup>e</sup>	C <sub>IN</sub>	f = 1 MHz	Room	7					pF
Dynamic Characteristics		•	•			•		•	
Turn-On Time	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room Full	88		118 160		118 144	
Turn-Off Time	t <sub>OFF</sub>	$V_S = \pm 10 V$ , See Figure 2	Room Full	69		97 120		97 112	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG456 only, $V_S = 10 V$ R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room	18					
Charge Injection <sup>e</sup>	Q	$V_{g} = 0 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	22					рС
Off Isolation <sup>e</sup>	OIRR	R <sub>I</sub> = 50 Ω, C <sub>I</sub> = 5 pF	Room	- 60					
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	f = 1  MHz	Room	- 85					dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>		Room	31					
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room	34					pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>		Room	103					г
Total Harmonic Distortion <sup>e</sup>	THD	Signal = 5 V <sub>RMS</sub> , 20 Hz to 20 kHz, R <sub>L</sub> = 600 $\Omega$	Room	0.04					%
Power Supplies									
Power Supply Current	l+		Room Full	25		100 100		100 100	
Negative Supply Current	Ι-	V+ = 16.5 V, V- = - 16.5 V V <sub>IN</sub> = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	I <sub>GND</sub>		Room Full	- 25	- 100 - 100		- 100 - 100		

SPECIFICATION	SPECIFICATIONS FOR DUAL SUPPLIES									
Parameter	Question	Test Conditions Unless Specified			- 40 °C t	o 125 °C	- 40 °C to 85 °C		11	
	Symbol	V+ = 5 V, V- = - 5 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	Temp. <sup>b</sup>	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit	
Analog Switch									_	
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 5	5	- 5	5	V	
On-Resistance	R <sub>ON</sub>	V+ = + 5 V, V- = - 5 V I <sub>S</sub> = - 10 mA, V <sub>D</sub> = - 3.5 V to + 3.5 V	Room Full	3.8		11 15		11 12	Ω	
On-Resistance Match	$\Delta R_{ON}$		Room Full	0.13		0.5 1		0.5 0.5	52	
Dynamic Characteristics	S	•				•		•		
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room Full	170		200 296		200 256		
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	V <sub>S</sub> = 3 V, See Figure 2	Room Full	66		96 124		96 113	ns	
Break-Before-Make <sup>e</sup> Time Delay	t <sub>D</sub>	DG456 only, V <sub>S</sub> = 3 V R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room	98						
Charge Injection <sup>e</sup>	Q	$V_{g} = 0 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	8					рС	

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SPECIFICATIONS FOR DUAL SUPPLIES									
Parameter Syn	Cumhal	Test Conditions Unless Specified	Temp. <sup>b</sup>		- 40 °C to 125 °C - 40 °C to			to 85 °C	Unit
	Symbol	V+ = 5 V, V- = - 5 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>			Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit
Power Supplies	Power Supplies								
Power Supply Current	l+		Room Full	14		100 100		100 100	
Negative Supply Current	I-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	I <sub>GND</sub>		Room Full	- 14	- 100 - 100		- 100 - 100		

		Test Conditions Unless Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	
Parameter	Symbol	V+ = 12 V, V- = 0 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	Temp. <sup>b</sup>	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit
Analog Switch									1
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full			12		12	V
On-Resistance	R <sub>ON</sub>	$I_{\rm S}$ = - 10 mA, $V_{\rm D}$ = 0 V to + 10 V	Room Full	5.5		8.1 12.4		8.1 10.4	
On-Resistance Match	$\Delta R_{ON}$	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = + 10 V	Room Full	0.14		0.5 1		0.5 0.5	Ω
On-Resistance Flatness	R <sub>FLATNESS</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = 0 V, + 5 V, + 10 V	Room Full	0.94		1.5 1.7		1.5 1.5	
Dynamic Characteristics							-		
Turn-On Time	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room Full	132		162 238		162 210	
Turn-Off Time	t <sub>OFF</sub>	$V_{S} = 8 V$ , See Figure 2	Room Full	61		91 117		91 105	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG456 only, V <sub>S</sub> = 8 V R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room	70					
Charge Injection <sup>e</sup>	Q	$V_g = 0 V$ , $R_g = 0 \Omega$ , $C_L = 1 nF$	Room	1					рС
Power Supplies	•				•	•		•	
Power Supply Current	l+		Room Full	25		100 100		100 100	
Negative Supply Current	I-	V+ = 13.5 V, V- = 0 V V <sub>IN</sub> = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μA
Ground Current	I <sub>GND</sub>		Room Full	- 25	- 100 - 100		- 100 - 100		

Notes:

a.  $V_{IN}$  = input voltage to perform proper function.

b. Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

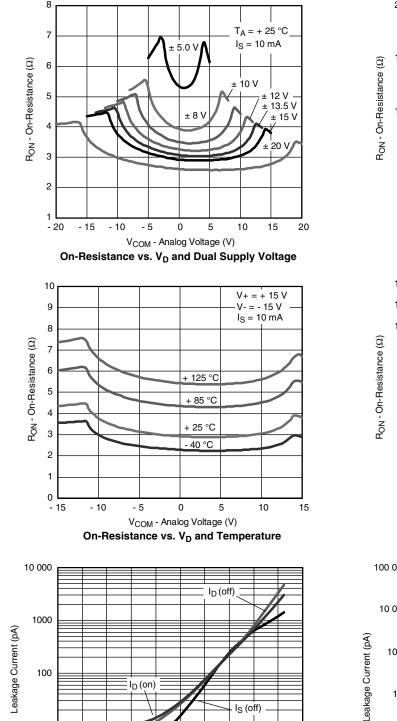
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

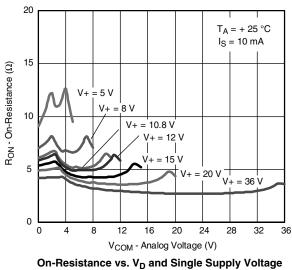
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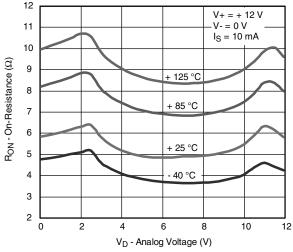


### DG454, DG455, DG456 Vishay Siliconix

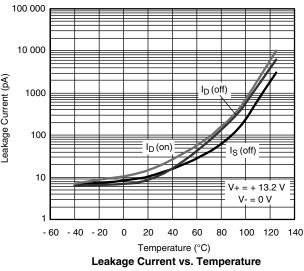
#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







On-Resistance vs.  $V_{\text{D}}$  and Temperature



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10

1 L

- 40 - 20

0 20 40 60

Temperature (°C)

Leakage Current vs. Temperature

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 $V_{+} = + 15 V$ 

V- = - 15 V

100

120 140

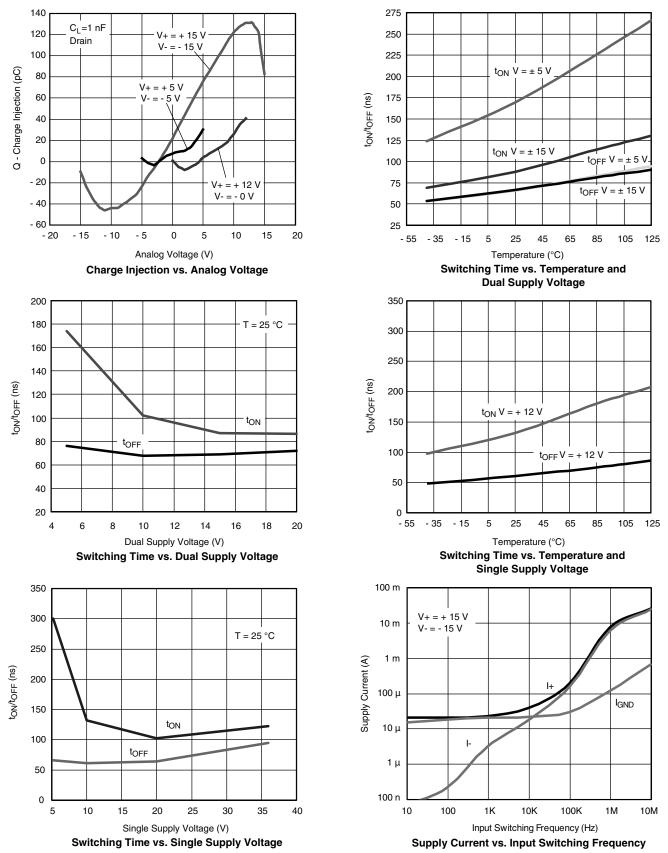
80

5

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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



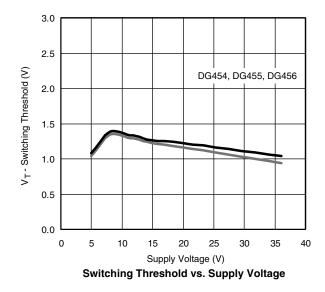
For technical questions, contact: analogswitchtechsupport@vishay.com

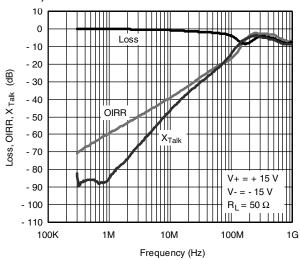
<sup>6</sup> 



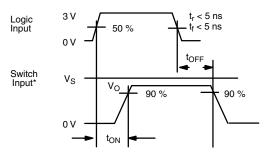
Vishay Siliconix

#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

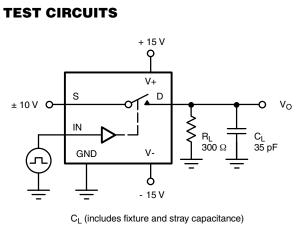




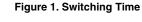
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



Note: Logic input waveform is inverted for switches that have the opposite logic sense control



$$V_{O} = V_{S} \qquad \frac{R_{L}}{R_{L} + R_{DS(on)}}$$



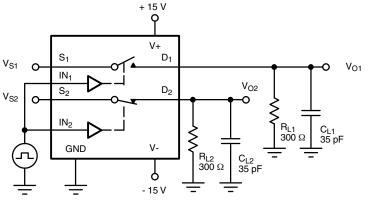
Logic Input

Switch

Output

Switch

Output

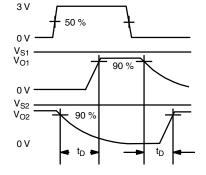




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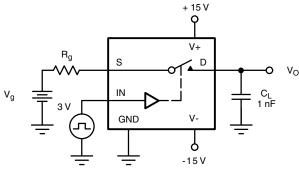
#### Figure 2. Break-Before-Make (DG456)



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#### **TEST CIRCUITS**



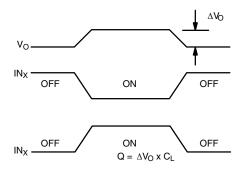
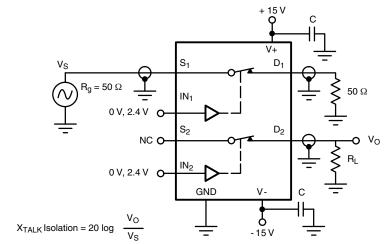
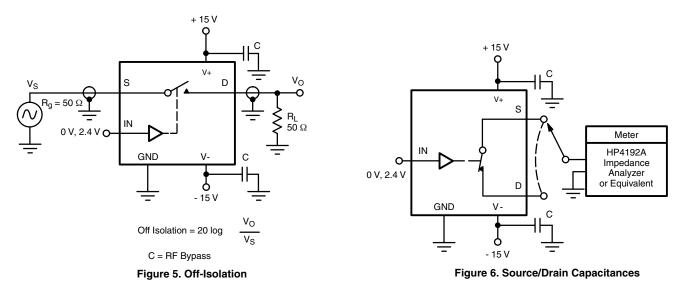


Figure 3. Charge Injection



C = RF bypass

Figure 4. Crosstalk



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?74473">www.vishay.com/ppg?74473</a>.

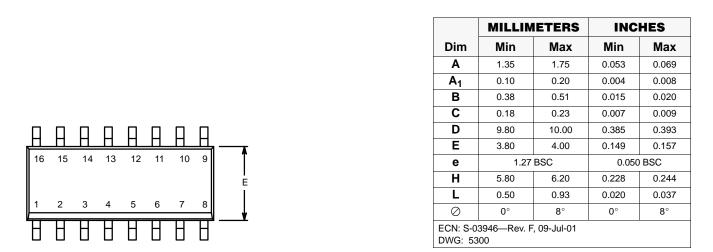


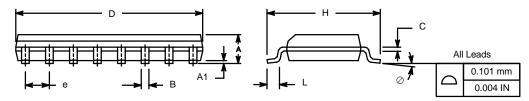




SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012



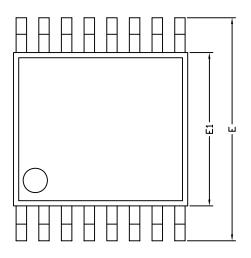




# Package Information

Vishay Siliconix

#### TSSOP: 16-LEAD





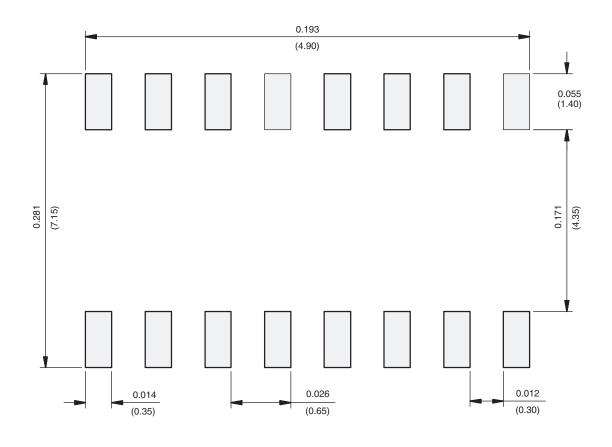
	C	IMENSIONS IN MILLIMETE	RS				
Symbols							
A	-	1.10	1.20				
A1	0.05	0.10	0.15				
A2	-	1.00	1.05				
В	0.22	0.28	0.38				
С	-	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	-	-	0.10				
θ1	0°	3°	6°				
ECN: S-61920-Rev. D, 23 DWG: 5624	-Oct-06						



**PAD** Pattern

Vishay Siliconix

#### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



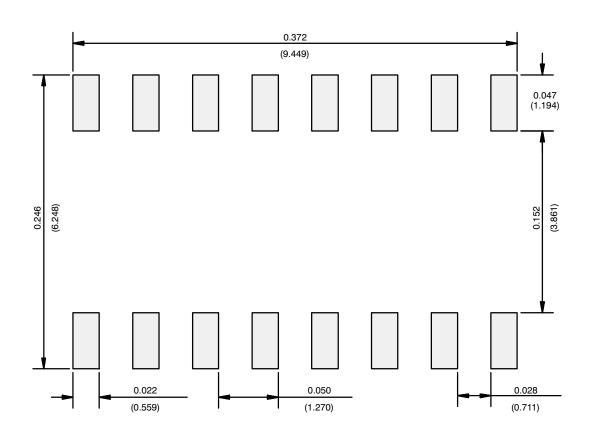
Recommended Minimum Pads Dimensions in inches (mm)

### **Application Note 826**

Vishay Siliconix



#### **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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Vishay

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